

DATA SHEET

OLF249: Radiation Tolerant Phototransistor Hermetic Surface Mount Optocoupler

Features

- Hermetic SMT package
- Compliant surface mounting leads
- · High current transfer ratio
- Small package size
- · High reliability and rugged construction
- High-reliability screening available
- Radiation tolerant

Description

The OLF249 consists of an LED that is optically coupled to an N-P-N silicon phototransistor mounted in an 8-pin hermetic surface mount flat-pack package. The leads can be formed to provide compliant solder connections to the mounting substrate.

Electrical parameters are similar to the JEDEC registered 4N49 optocoupler, but with much better current transfer ratio (CTR) degradation characteristics due to radiation exposure. Special electrical parametric selections are available on request.

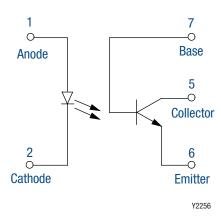


Figure 1. OLF249 Block Diagram

Figure 1 shows the OLF249 functional block diagram. Table 1 provides the OLF249 absolute maximum ratings. Table 2 provides the OLF249 electrical specifications.

Figures 2 through 4 illustrate the OLF249 typical performance characteristics. Figure 5 shows the OLF249 switching test circuit. Figure 6 provides the OLF249 package dimensions.

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Table 1. OLF249 Absolute Maximum Ratings (Note 1)

Parameter	Symbol	Minimum	Maximum	Units
Coupled	·			
Input to output isolation voltage (Note 2)	VDC		±1000	V
Storage temperature	Тѕтс	-65	+150	°C
Operating temperature	TA	-55	+125	°C
Mounting temperature (10 seconds maximum)	Тмтс		+240	°C
Input Diode				
Average input current (Note 3)	loo		40	mA
Peak forward current (≤ 1 ms duration) (Note 4)	l _F		1	Α
Reverse voltage	Vr		2	V
Output Detector				
Collector to emitter voltage	Vce		40	V
Emitter to base voltage	VEB		7	V
Collector to base voltage	Vcв		45	V
Continuous collector current	Icc		50	mA
Power dissipation (Note 5)	Po		300	mW

Note 1: Exposure to maximum rating conditions for extended periods may reduce device reliability. There is no damage to the device with only one parameter set at the limit and all other parameters set at or below their nominal value. Exceeding any of the limits listed here may result in permanent damage to the device.

Note 4: For pulse width $\leq 1~\mu s$, pulse repetition rate $\leq 300~pps$.

Note 5: Derate linearly to 125 °C free-air temperature at 3.0 mW/°C above 25 °C.

CAUTION: Although this device is designed to be as robust as possible, electrostatic discharge (ESD) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions should be used at all times.

Note 2: Measured between pins 1, 2, 3, and 4 shorted together, and pins 5, 6, 7, and 8 shorted together. TA = 25°C and duration = 1 second.

Note 3: Derate linearly to 125 °C free-air temperature at 0.67 mA/°C above 65 °C.

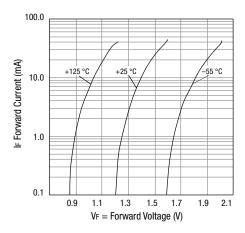
Table 2. OLF249 Electrical Specifications (Note 1) ($T_A = 25$ °C, Unless Otherwise Noted)

Parameter	Symbol	Test Condition	Minimum	Maximum	Units
On-state:					
Collector current	Іс_ом	IF = 1 mA, Vce = 5 V IF = +2 mA, Vce = +5 V, Ta = -55 °C IF = 2 mA, Vce = 5 V, Ta = 100 °C	2.0 2.8 2.0	12.0	mA mA mA
Collector base current	ICB_ON	$I_F = 10 \text{ mA}, V_{CB} = 5 \text{ V}$	30		μΑ
Saturation voltage	Vce_sat	$I_F = 2 \text{ mA}, I_C = 2 \text{ mA}$		0.3	٧
Breakdown voltage:					
Collector to emitter Collector to base Emitter to base	BVceo BVcbo BVebo	ICE = 1 mA ICB = 100 μA IEB = 100 μA	40 45 7		V
Off-state leakage current:					
Collector to emitter	ICE_OFF	Vce = 20 V Vce = 20 V, Ta = 100 °C		100 100	nA μA
Collector to base	ICB_OFF	Vcb = 20 V		10	nA
Input:					
Forward voltage	VF	$I_F = +10 \text{ mA}, T_A = -55 ^{\circ}\text{C}$ $I_F = 10 \text{ mA}$ $I_F = 10 \text{ mA}, T_A = +100 ^{\circ}\text{C}$	1.4 1.2 1.1	2.0 1.8 1.7	V V V
Reverse current	l _R	$V_R = 2 V$		100	μΑ
Output resistance (Note 2)	rı_o	Vi-o = ±1000 Vpc	10 ¹¹		Ω
Output capacitance (Note 2)	CI_0	$V_{I-0} = 0 \ V, f = 1 \ MHz$		5	pF
Times:					
Rise Fall	tr tr	Vcc = 10 V, RL = 100 Ω IF = 5 mA		25 25	μs μs

Note 1: Performance is guaranteed only under the conditions listed in the above table.

Note 2: Measured between pins 1, 2, 3, and 4 shorted together, and pins 5, 6, 7, and 8 shorted together. TA = 25°C and duration = 1 second.

Typical Performance Characteristics





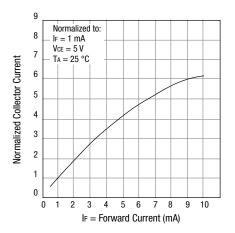


Figure 3. Normalized Collector Current vs Forward Current

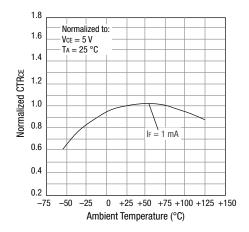


Figure 4. Normalized CTRCE vs Temperature

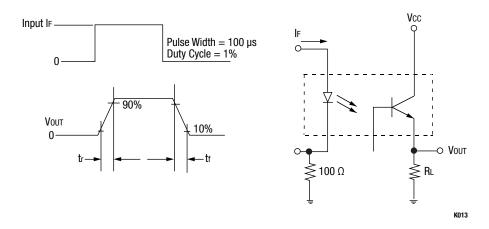


Figure 5. OLF249 Switching Test Circuit

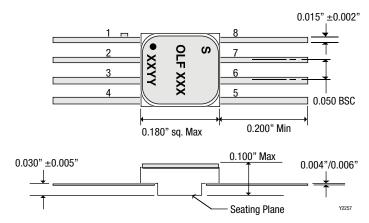


Figure 6. OLF249 Package Dimensions

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Ordering Information

Model Name	Manufacturing Part Number		
OLF249: Radiation Tolerant Phototransistor Hermetic Surface Mount Optocoupler	0LF249		

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